Planar Magnetic Integration Design Based on LLC Resonant Converter

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Abstract - High power density and high efficiency is a major trend in the development of power converters. The main measure to reduce the size of power converter is to improve the working frequency, and the limiting factor is the size of magnetic components. With the development of new semiconductor devices, the working frequency of power converters has been significantly improved, which gives us the opportunity to apply printed circuit board (PCB) winding planar magnetics. Compared with the traditional high frequency magnetics, planar magnetics not only reduce the size of the magnetic components effectively but also improve reliability through repeatable automated manufacturing, which is convenient for large-scale production. Magnetic integration is another method to reduce the size of the power converter. In this paper, a new magnetic structure based on PCB winding is proposed, which integrates inductance and transformer into one component. And the inductor can be independent of the transformer. In this structure, the inductance of inductor and excitation inductance of transformer can be easily controlled by changing the number of winding turns or the length of the air gap. A 20-W 200-kHz halfbridge LLC resonant converter with a peak efficiency of 94.9% is built to verify the feasibility of the designed planar magnetic integrated structure.

Index Terms – High frequency, printed circuit board (PCB) transformer, magnetic integration, LLC resonant converter.

I. INTRODUCTION

Nowadays, power electronic converters with high power density and high efficiency play a significant role in data center, aerospace, communication, and other fields. As an important part of power converter, the magnetic components including inductor and transformer are actually the limitation to reduce the size and weight of the power converter system. In addition, the production process of traditional magnetic components is complex and labor-intensive, which has become an impediment to the automatic production of power electronic converters. In recent years, with the rapid development of printed circuit boards (PCBs), low-altitude power electronic converter has become a research hotspot. Planar magnetic structure can not only reduce the size of magnetic components but also improve the reliability through repeatable automatic manufacturing and better control of parasitic parameters. However, at low operating frequency, the cost and excessive winding turns limit the application of PCB magnetic components in power converters [1–5].

With the development of power electronics, the working frequency of the power converter increases to hundreds of kilohertz, even megahertz. At higher switching frequency, it can not only reduce the size of magnetic components but also reduce the coil turns of magnetic components, making PCB winding planar magnetic components more practical. In [6], the transformer on 65-W flyback circuit adopts PCB planar transformer. In [7] and [8], the application of PCB transformer in LLC resonant converter can significantly reduce the size of the converter and improve the power density.

Although planar magnetic components have many advantages, there are still many problems, such as multiple magnetic components and large volume. Fortunately, magnetic integration technology is an effective method to solve the above problems. Through magnetic integration, multiple magnetic components can be integrated into one magnetic component, which can effectively reduce the number of magnetic components of power converter and improve the power density.

In order to reduce the number of magnetic components and the size of the power converter, several methods of magnetic integration are often adopted. A common method is to realize the inductance function through the leakage inductance of the transformer. Several theoretical methods have been proposed to design leakage inductance of transformers. Some of them use low permeability materials as additional magnetic circuit, resulting in increased leakage inductance [9–11]. However, this will change the structure of the transformer and make its production process more complex. Due to the characteristics of low permeability materials, the core loss of magnetic components will increase and the overall efficiency of the converter will decrease. In addition, it is also popular to wind the primary winding and the secondary winding separately to obtain the required leakage inductance [12–14]. This method can lead to serious electromagnetic interference (EMI) problems, additional eddy current losses, and increased AC losses in the windings. In addition, due to the low profile characteristics of the winding transformer on PCB, this structure is difficult to be applied to it [15].

In this paper, a novel winding structure based on planar core is proposed. The inductor and transformer are integrated through an EI planar core, and they are decoupled. With this structure, the excitation inductance of the transformer and the inductance of the inductor can be adjusted by the air gap of the core or the number of turns of the winding. Because the leakage inductance of the transformer is not used as inductance, the EMI and eddy current loss are effectively reduced.

The structure of this paper is as follows. In Section II, a new type of magnetic integrated structure including inductor and transformer is proposed, the equivalent model is established, and the decoupling mechanism and calculation formula are deduced. In Section III, magnetic integrated components are applied to half-bridge LLC resonant transformer and the selection formula of planar core size is derived. In Section IV, simulation parameters of half-bridge LLC resonant converter are determined, and the simulation analysis of magnetic integrated components is carried out. In Section V, the experimental verification is carried out. Section VI summarizes the whole paper.

II. STRUCTURE AND ANALYSIS OF PLANAR MAGNETIC INTEGRATION A. Planar magnetic integration of inductor and transformer

The structure of the inductor integrated with the transformer is shown in Figure 1. In order to effectively use the magnetic core and decouple the inductor and transformer, the resonant inductor is wound around the side legs of the magnetic core, the primary and secondary sides of transformer are wound around the middle leg of the magnetic core, and air gaps of the same length are opened for the three magnetic legs.

In Figure 1, N_P and N_S are the turns of primary and secondary windings of the transformer, N_{r1} and N_{r2} are the turns of the inductor windings around the left and right poles of the magnetic core, L_P and L_S are the selfinductance of the primary and secondary windings of the transformer, respectively, L_{r1} and L_{r2} are the inductance of windings around the respective side legs, the sum of L_{r1} and L_{r2} inductance is the inductance of resonant inductance L_r , V_{Lr1} and V_{Lr2} are the inductance volt-



Fig. 1. Structure diagram of planar magnetic integration.

ages of the left and right legs, respectively, V_P and V_S are the voltages of primary and secondary windings of the transformer, respectively, R_{m1} , R_{m2} , and R_{m3} are the magnetoresistance of two side legs and the middle leg, respectively, and Φ_{Lr1} , Φ_{Lr2} , and Φ_T are the magnetic flux generated by the left and right column windings and the magnetic flux generated by the transformer winding, respectively.

In the design, three cylinders of the magnetic core have air gaps with the same length. For the EI-type magnetic core, the area of the column is the sum of the areas of the two side legs:

$$R_{m1} = R_{m2} = 2R_{m3} = 2R_m. \tag{1}$$

In formula (1), R_m is the air gap magnetoresistance of the middle leg of the magnetic core. According to the magnetic circuit of the magnetic integrated element, the equivalent magnetic circuit diagram is obtained, as shown in Figure 2. In this figure, Φ_1 , Φ_2 , and Φ_3 , respectively, represent the magnetic flux of the two side legs and the center leg of the magnetic core. $N_{Lr1}i_{Lr1}$, $N_{Lr2}i_{Lr2}$, N_pi_p , and N_si_s , respectively, represent the magnetic potential of the inductor windings of the two side legs, and the magnetic potential of the primary and secondary side windings of the transformer.

As shown in the above design structure, the total magnetic flux generated by the inductor winding on the side leg of the core does not affect the magnetic flux of the transformer winding and vice versa. In this structure, the inductor and the transformer can be completely decoupled.

B. Principal analysis of integrated magnetic element

According to the equivalent diagram of magnetic circuit in Figure 2, combined with Ohm's law of magnetic circuit and Faraday's law of electromagnetic induc-



Fig. 2. Equivalent diagram of magnetic circuit.

tion, the following formulas are deduced. First, the magnetic flux generated by each winding is as follows [16]:

$$\begin{cases} \Phi_{Lr1} = \frac{N_{Lr1}i_{Lr1}}{R_{m1} + R_{m2}//R_{m3}} = \frac{N_{Lr1}i_{Lr1}(R_{m2} + R_{m3})}{8R_{m}} \\ \Phi_{Lr2} = \frac{N_{Lr2}i_{Lr2}}{R_{m2} + R_{m1}//R_{m3}} = \frac{N_{Lr2}i_{Lr2}(R_{m1} + R_{m3})}{8R_{m}} \\ \Phi_{T} = \frac{N_{p}i_{p} - N_{s}i_{s}}{R_{m3} + R_{m1}//R_{m2}} = \frac{(N_{p}i_{p} - N_{s}i_{s})(R_{m1} + R_{m2})}{2R_{m}} \end{cases}$$
(2)

According to the magnetic circuit diagram of the planar magnetic integrated structure shown in Figure 2, the magnetic flux of each cylinder of the magnetic core is obtained as follows:

$$\begin{cases} \Phi_{1} = \Phi_{Lr1} + \Phi_{T} \frac{R_{m2}}{R_{m1} + R_{m2}} + \Phi_{Lr2} \frac{R_{m3}}{R_{m1} + R_{m3}} \\ \Phi_{2} = \Phi_{Lr2} - \Phi_{T} \frac{R_{m1}}{R_{m1} + R_{2}} + \Phi_{Lr1} \frac{R_{m3}}{R_{m2} + R_{m3}} \\ \Phi_{3} = \Phi_{T} + \Phi_{Lr1} \frac{R_{m2}}{R_{m2} + R_{m3}} + \Phi_{Lr2} \frac{R_{m1}}{R_{m1} + R_{m3}} \end{cases}$$
(3)

And because the voltage V_{Lr} of the inductance L_r is the sum of V_{Lr1} and V_{Lr2} , and the current i_{Lr} flowing through the inductance L_r is equal to i_{Lr1} and i_{Lr2} , where i_{Lr1} and i_{Lr2} are the current flowing through the left and right side column inductance windings respectively. And according to the law of electromagnetic induction, primary winding voltage V_p , secondary winding voltage V_s , and inductance winding voltage V_{Lr} are as follows:

$$\begin{cases}
V_{p} = N_{p} \frac{d\Phi_{3}}{dt} \\
V_{s} = -N_{s} \frac{d\Phi_{3}}{dt} \\
V_{Lr} = V_{Lr1} + V_{Lr2} = N_{Lr1} \frac{d\Phi_{1}}{dt} + N_{Lr2} \frac{d\Phi_{2}}{dt}
\end{cases}$$
(4)

According to all the above equations, the relationship between voltage and current of planar magnetic integrated components is derived

$$\begin{bmatrix} V_{Lr} \\ V_p \\ V_s \end{bmatrix} = \begin{bmatrix} L_r & M_{pLr} & M_{sLr} \\ M_{pLr} & L_p & -M_{ps} \\ M_{sLr} & -M_{ps} & L_s \end{bmatrix} \begin{bmatrix} \frac{di_{Lr}}{dt} \\ \frac{di_p}{dt} \\ \frac{di_s}{dt} \end{bmatrix}.$$
 (5)

In formula (5), i_p and i_s are, respectively, the current flowing through the primary and secondary windings of the transformer, and M_{pLr} , M_{sLr} , and M_{ps} , respectively, represent the mutual inductance between the primary winding N_p of the transformer and the inductance L_r , the mutual inductance between the winding N_s on secondary side of the transformer and the inductance L_r , and the mutual inductance between the primary winding N_p of the transformer and the secondary winding N_s of the transformer. Formula (6) is obtained by solving the above formula

$$\begin{cases}
L_{s} = \frac{N_{s}^{2}}{2R_{m}} \\
L_{s} = \frac{N_{s}^{2}}{2R_{m}} \\
L_{r} = \frac{3N_{Lr1}^{2} + 3N_{Lr2}^{2}}{8R_{m}} + \frac{N_{Lr1}N_{Lr2}}{4R_{m}} \\
M_{pLr} = \frac{N_{p}(N_{Lr1} - N_{Lr2})}{4R_{m}} \\
M_{sLr} = \frac{N_{s}(N_{Lr2} - N_{Lr1})}{4R_{m}} \\
M_{ps} = \frac{N_{p}N_{s}}{2R_{m}}
\end{cases}$$
(6)

By simplifying formula (6), formula (7) is obtained as follows:

$$\begin{cases} k_{\rm ps} = \frac{-M_{\rm ps}}{\sqrt{L_{\rm p}L_{\rm s}}} = -1 \\ k_{\rm pLr} = \frac{M_{\rm pLr}}{\sqrt{L_{\rm r}L_{\rm p}}} = \frac{N_{Lr2} - N_{Lr1}}{\sqrt{3N_{Lr1}^2 + 3N_{Lr2}^2 + 6N_{Lr1}N_{Lr2}}} \\ k_{\rm sLr} = \frac{-M_{\rm sLr}}{\sqrt{L_{\rm r}L_{\rm s}}} = \frac{N_{Lr1} - N_{Lr2}}{\sqrt{3N_{Lr1}^2 + 3N_{Lr2}^2 + 6N_{Lr1}N_{Lr2}}} \end{cases}$$
(7)

In formula (7), k_{ps} , k_{pLr} , and k_{sLr} , respectively, represent the coupling coefficients between L_P and L_S , L_P and L_r , and L_S and L_r .

According to the above formula, the coupling coefficient *k* between the inductor and the transformer can be obtained by changing the turns of the windings N_{Lr1} and N_{Lr2} around the two side legs of the planar transformer core. When $N_{Lr1} = N_{Lr2}$, the coupling coefficient k_{pLr} $= k_{sLr} = 0$ between the primary and secondary windings and the inductance of the transformer is 0. At this time, they will not affect each other in the working process, and the decoupling integration between the inductance and the transformer is realized.

III. ANALYSIS AND DESIGN OF INTEGRATED MAGNETIC ELEMENT A. Structure of LLC resonant converter based on magnetic integration

For half-bridge LLC resonant converter, the back stage rectifier can be divided into full wave rectifier with central tap of transformer and bridge rectifier without central tap of transformer. The first scheme is suitable for the application of low voltage and high current, and the second scheme is suitable for the application of high voltage and low current. The planar transformer integration based on inductors completely decoupled from transformers is suitable for both schemes, and the primary and secondary sides of the inductor and transformer can be completely decoupled [17–19]. The structure diagram of LLC resonant converter using the designed magnetic integrated elements is shown in Figure 3.

The planar magnetic integrated transformer is applied to the half-bridge LLC series resonant converter. There are two resonant frequencies in the half-bridge LLC resonant converter, f_{r1} and f_{r2} . f_{r1} is the resonant frequency of inductance L_r and capacitor C_r , and f_{r2} is the frequency at which the sum of inductance L_r and excitation inductance L_m of the transformer resonates with the capacitor. In order to maximize efficiency, the working range of the frequency is set between f_{r2} and f_{r1} , and the current works in a discontinuous mode (DCM). In this case, not only ZVS of the switch can be turned on, but also the rectifier diode on the secondary side can be turned off at zero current. The main waveforms of the converter operating between f_{r2} and f_{r1} are shown in Figure 4.

B. Design and selection of integrated magnetic elements

Figure 5 shows the air gap and cross-section of the integrated magnetic elements; l_g is the length of the air gap of the planar transformer magnetic core. For the convenience of the design, the three cylinders of the EI core have the same air gap. S_1 , S_2 , and S_3 represent the core



Fig. 3. Half-bridge LLC resonant converter based on magnetic integration.



Fig. 4. Main waveforms of LLC when $f_{r2} < f_s < f_{r1}$.



Fig. 5. Air gap and cross-section of planar integrated magnetic elements. (a) Air gap of EI core. (b) Cross-sectional area of magnetic core.

cross-sectional area of two side columns and a central column of the planar transformer, respectively. Since EI magnetic core is selected, $S_3 = 2S_1 = 2S_2$.

Formula (8) represents the magnetoresistance of each cylinder of the integrated magnetic element, where μ_0 represents the air permeability

$$\begin{cases}
R_{g1} = \frac{l_g}{\mu_0 S_1} \\
R_{g2} = \frac{l_g}{\mu_0 S_2} \\
R_{g3} = \frac{l_g}{\mu_0 S_3}
\end{cases}$$
(8)

In order to analyze the magnetic density variation of the integrated magnetic element applied in the LLC resonant converter, we select the continuous phase in Figure 4 because the magnetic element of LLC resonant converter is bidirectionally excited and has periodicity. In t_3-t_6 , the rectifier diode of the secondary side of the transformer is switched on, the voltage of the primary winding of the transformer is clamped to nV_0 , and the voltage of the secondary winding is $-V_0$; so V_s can be expressed as

$$V_{\rm s} = -V_0 = -N_{\rm s} \frac{{\rm d}\Phi_3}{{\rm d}t} \ (t_3 \le t \le t_6).$$
 (9)

For the center leg III of the core, the magnetic flux of both sides of the cylinder will not pass through, and the magnetic flux density of the center column reaches the maximum value during t_3-t_6 . According to formula (9), the maximum magnetic density B_{3max} of the middle column is

$$B_{3\max} = \frac{\Phi_{3\max}}{S_3} = \frac{V_0}{2S_3N_s}(t_6 - t_3).$$
(10)

When the half-bridge LLC converter operates in modes 3, 4, 5, and 6, there are

$$V_{Lr} = V_{in} - V_p - V_{Cr}$$

= $N_{Lx1} \frac{d\Phi_1}{dt} + N_{Lx2} \frac{d\Phi_2}{dt} \quad (t_2 \le t \le t_6).$ (11)

At t_6 , the magnetic density of core side leg I reaches the maximum value, and because $\Phi_1=\Phi_2+\Phi_3$, the maximum magnetic density B_{1max} is obtained as follows:

$$B_{1\max} = \frac{\Phi_{1\max}}{S_1} = k_1 \frac{\left[\frac{V_o(N_p - N_{Lr2})}{N_s}\right](t_6 - t_2)}{2S_1(N_{Lr1} + N_{Lr2})}.$$
 (12)

In the calculation, the voltage of the winding is equal to the DC voltage. In practical application, the voltage will change due to resonance and the actual flux density will be slightly less than the obtained flux density. Therefore, the coefficient k_1 is introduced to obtain the real flux density, and the value of k_1 is about 0.7–0.9.

For the maximum flux density B_{2max} of the magnetic leg II, when the resonant current of the inductor reaches the maximum or minimum value, the flux density reaches the maximum value and the converter operates at $t_5 < t < t_{5.6}$. The magnetic density began to increase at $t_{5.6}$. According to formula (12) and $\Phi_1=\Phi_2+\Phi_3$, B_{2max} can be obtained as follows:

$$B_{2\max} = \frac{\Phi_{2\max}}{S_2} = k_2 \frac{\left[\frac{V_0(N_p + N_{Lr2})}{2N_s}\right](t_{5.6} - t_3)}{2S_2(N_{Lr1} + N_{Lr2})}.$$
 (13)

In the same way as formula (12), the voltage of the winding is equal to the DC voltage. Therefore, the coefficient k_2 is introduced to obtain the real flux density of cylinder II, and the value of k_2 is about 0.7–0.9.

Through the above formula, we can verify whether the selected magnetic core is reasonable. Because the magnetic flux cancelation effect will occur in cylinder III and cylinder II, the magnetic flux density of cylinder I and cylinder III will not be offset but will be

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Specifications	Values
Resonant frequency	200 kHz
Input voltage range	60-80 V
Output voltage	10 V
Power	20 W
Turn ratio of transformer	4:1
Resonant inductor	20 µH
Excitation inductance	56 µH
Resonant capacitor	33 nF

superimposed. Therefore, it is only necessary to ensure that cylinder I is not saturated and the other two cylinders will not be saturated. In formula (11), t_6-t_2 is about half of a cycle; so formula (11) can be simplified as follows:

$$B_{1\max} = \frac{\Phi_{1\max}}{S_1} = k_1 \frac{\left[\frac{V_o(N_p - N_{Lr2})}{N_s}\right]}{2S_1(N_{Lr1} + N_{Lr2})f}.$$
 (14)

In formula (14), f is the working frequency of half-bridge LLC resonant converter. In the calculation, the minimum value of working frequency should be selected.

For the selection of the magnetic core size under the determined power, first, select the type under the worst working conditions. According to formula (14), ensure that the maximum magnetic flux density will not saturate the magnetic core at this time, and the coefficient k_1 in the formula has guaranteed the magnetic flux density margin.

IV. SIMULATION ANALYSIS OF PLANAR MAGNETIC INTEGRATION

A. Parameter setting

In the design, we make LLC resonant converter work between f_{r2} and f_{r1} , which can not only realize soft switching but also realize ZCS of secondary rectifier diode. According to the input voltage range, the working frequency range of LLC resonant converter is 125–180kHz. The main parameters of half-bridge LLC resonant converter are shown in Table 1.

The planar EI core is made of PC95 ferrite EI22/8/16. The structure of E core and I core is shown in Figure 6, and the specific core parameters are shown in Table 2.

For the method of setting air gap, we use 0.06-mm air gap gasket to ensure that the air gap of each cylinder is the same. According to formulas (6) and (7), the number of turns of the inductor on the side leg of the planar magnetic core is calculated as 4 turns, the number of original side turns of the transformer is 8 turns, and the number of secondary side turns of the transformer is 2 turns.



Fig. 6. Structure and size of E core and I core.

Table 2: Core parameters

Cylinder	Area/mm ²	Air gap/mm	Reluctance/10⁶H ⁻¹
Ι	40	0.06	1.193
II	80	0.06	0.598
III	40	0.06	1.193

According to the formula deduced in Section III and the design parameters of LLC resonant converter, the maximum magnetic flux density is only 0.27T, while the saturated magnetic flux density of PC95 EI22/8/16 magnetic core is 0.55T, which verifies the rationality of the selected magnetic core.

B. Simulation analysis

According to the design parameters of the planar magnetic integrated elements, the finite element analysis model of the magnetic integrated elements is established in Ansys Maxwell electromagnetic field simulation software. Considering the influence of simulation accuracy and computer performance, the mesh is divided based on the edge length of the inside element of the model, and the set length is 0.5 mm. According to a series of parameters of half-bridge LLC resonant converter design, an open-loop circuit is built in Maxwell circuit design and imported into Ansys Maxwell, the external circuit structure is shown in Figure 7. In the figure, Lwinding1 and Lwinding2 are the resonant inductance of the resonant cavity, Lwinding3 is the excitation inductance of the primary side of the transformer, and Lwinding4 and Lwinding5 are the excitation inductance of the secondary side of the transformer. This circuit is used as the external excitation source of the planar magnetic integrated model, and its parameters are set as input 60 V, switching frequency 125 kHz, and output rated load. After the simulation, observe whether the soft switching and zero current shutdown of the secondary side are realized and obtain the resonant current and driving waveforms of the down transistor and the current and voltage waveforms of



Fig. 7. External circuit structure diagram of simulation.



Fig. 8. Resonant current and S_2 driving waveforms.



Fig. 9. Current and voltage waveforms of rectifier D_2 .

the secondary rectifier tube. These waveforms are shown in Figures 8, and 9.

According to Figure 8, when S_2 starts to turn on, the resonant current is positive. At this time, the body diode of S_2 has conducted the freewheeling current, realizing ZVS of MOSFET. In Figure 9, when the current flowing through the rectifier diode is 0, the reverse voltage begins to increase. Therefore, the zero current shutdown of the rectifier diode is realized. In the figure, when the diode is on, it has a negative voltage because of the voltage drop. When analyzing the iron loss of the magnetic integrated structure, the parameters of PC95 material are imported



Fig. 10. Magnetic flux density of planar magnetic integrated elements.

into the software, and it is concluded that the core loss changes periodically. According to the calculation, the average core loss is about 0.41 W.

In the Ansys Maxwell-3D simulation environment, the model of planar magnetic integrated components is established, the external circuit is drawn, and the flux density distribution of planar magnetic integrated components is obtained by co-simulation. As shown in Figure 10, the maximum magnetic flux density of the magnetic integrated component is 0.285T, which is not different from the maximum magnetic flux density deduced from the formula. The rationality of the magnetic core selection is proved.

V. EXPERIMENTAL VERIFICATION

In order to verify the correctness and superiority of the structure design of planar magnetic integrated magnetic elements, an experimental prototype is built as shown in Figure 11.

Some winding configurations are shown in Figure 12, where (a) and (b) are the windings of the inductor, (c) is the primary winding of the transformer, and (d) is the secondary winding of the transformer. Each layer is connected through vias. The yellow arrow indicates the flow direction of the current in the primary



Fig. 11. Testing system of LLC resonant converter.



Fig. 12. Partial winding arrangement. (a) Layer 1. (b) Layer 2. (c) Layer 3. (d) Layer 4.

winding and the red arrow indicates the flow direction of the current in the secondary winding.

When the input voltage is 60 V and the output voltage is 10 V, the resonant current and the waveform of switching tube S_2 and the current and voltage waveforms of rectifier diode D_2 are shown in Figure 13. When the input voltage is 80 V and the output voltage is 10 V, the current and voltage waveforms of rectifier diode D_2 are shown in Figure 14.

According to Figures 13 and 14, when the driving voltage of the lower tube S_2 increases, that is, when the lower tube is on, the resonant current is positive. At this time, the body diode of S_2 has been turned on, realizing ZVS of the switching tube. When the current of rectifier diode is 0, the reverse voltage of the diode begins to increase, and ZCS of the secondary diode is realized. According to the oscilloscope, the working frequency is between 133 and 169 kHz, and the effective value of resonant current is 0.594–0.939A, which is basically consistent with the design parameters.

In order to compare the integrated magnetic components with the discrete magnetic components, the geometric dimensions and parameters of each magnetic component are given in Table 3. The volume of the integrated magnetic component is 2040 mm³ and the mass is 10.5 g. Compared with the discrete magnetic



Fig. 13. Waveforms at 60-V input. (a) Resonant current and driving voltage waveforms. (b) Waveforms of diode current and reverse voltage.

Tabl	le 3	3: 1	Comparison	of core	size	and	mass
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Magnetic 1	Core	Volume/mm ³	Quality/g	
Discreteness	Inductance	EE19	910	4.9
Discreteness	Transformer	EE20	1450	7.6
Integrati	EI22	2040	10.5	

elements, the volume and weight of the planar integrated magnetic elements are reduced by 13.56% and 16%, respectively. For the whole circuit board, the power density is increased by 15%.

Under the same conditions, the efficiency comparison curve of half-bridge LLC resonant transformer is obtained by testing the discrete magnetic devices and integrated devices, as shown in Figure 15. Compared with the traditional discrete magnetic components, the planar core has a larger body ratio and is more conducive to heat dissipation. Due to the magnetic flux cancelation effect, the core loss is reduced. When the output current is 2.2 A, the efficiency reaches the maximum in both cases. At this time, the corresponding efficiency of the discrete magnetic components is 94.2%, and the efficiency of the integrated magnetic components is 94.9%. Within full load range, the efficiency of planar



Fig. 14. Waveforms at 80-V input. (a) Resonant current and driving voltage waveforms. (b) Waveforms of diode current and reverse voltage.



Fig. 15. Efficiency comparison curve.

integrated magnetic components is significantly higher than that of discrete magnetic components, and the efficiency curves have the same trend.

VI. CONCLUSION

In this paper, a planar magnetic integrated component based on independent inductance is proposed. The inductor and transformer are integrated on a planar magnetic core by the decoupling integration method and the inductor and transformer are decoupled completely. It is applied to half-bridge LLC resonant converter. It is proved that there is no coupling between the inductor and transformer by the formula derivation, and the design and selection methods of magnetic integrated components are proposed. The excitation inductance of the inductor and transformer can be easily controlled by changing the air gap and winding turns. In addition, the electromagnetic field characteristics of planar magnetic integrated components are analyzed in the simulation software. Finally, a 20-W 200-kHz half-bridge LLC resonant converter is built, which achieves good soft switching performance in the whole load range, and the peak efficiency reaches 94.9%.

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